TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74ACT245P,TC74ACT245F,TC74ACT245FW,TC74ACT245FT TC74ACT640P,TC74ACT640F,TC74ACT640FW,TC74ACT640FT

Octal Bus Transceiver

TC74ACT245P/F/FW/FT 3-State, Non-Inverting TC74ACT640P/F/FW/FT 3-State, Inverting

The TC74ACT245 and 640 are advanced high speed CMOS OCTAL BUS TRANSCEIVERs fabricated with silicon gate and double-layer metal wiring C<sup>2</sup>MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

These devices may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

They are intended for two-way asynchronous communication between data busses. The direction of data transmission is determined by the level of the DIR input.

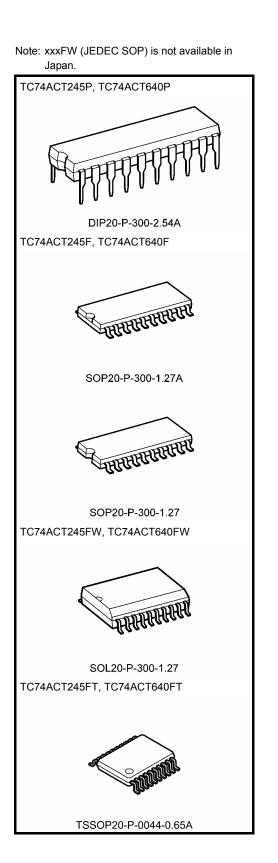
The enable input (  $\overline{\rm G}$  ) can be used to disable the device so that the busses are effectively isolated.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

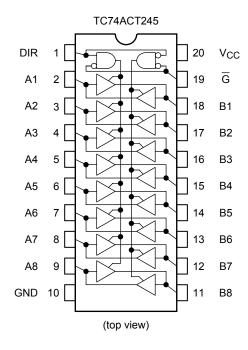
# Features (Note 1) (Note 2)

- High speed: t<sub>pd</sub> = 4.7 ns (typ.) at V<sub>CC</sub> = 5 V
- Low power dissipation:  $I_{CC} = 8 \ \mu A \ (max)$  at  $Ta = 25^{\circ}C$
- Compatible with TTL outputs : V<sub>IL</sub> = 0.8 V (max), V<sub>IH</sub> = 2.0 V (min)
- Symmetrical output impedance :  $|I_{OH}| = I_{OL} = 24$  mA (min) Capability of driving 50  $\Omega$  transmission lines.
- Balanced propagation delays:  $t_{pLH} \simeq t_{pHL}$
- Pin and function compatible with 74F245/640
  - Note 1: Do not apply a signal to any bus terminal when it is in the output mode. Damage may result.
  - Note 2: All floating (high impedance) bus terminals must have their input levels fixed by means of pull up or pull down resistors.

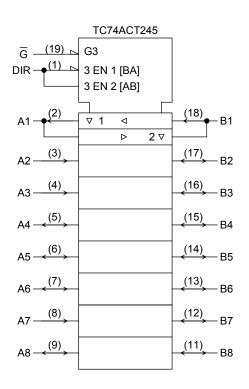
Weight	
DIP20-P-300-2.54A	: 1.30 g (typ.)
SOP20-P-300-1.27A	: 0.22 g (typ.)
SOP20-P-300-1.27	: 0.22 g (typ.)
SOL20-P-300-1.27	: 0.46 g (typ.)
TSSOP20-P-0044-0.65A	: 0.08 g (typ.)

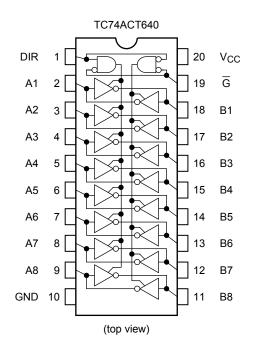


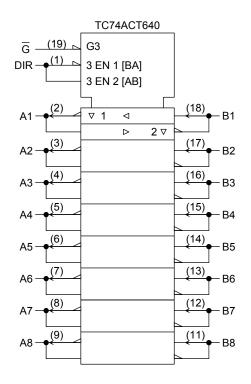
# **Pin Assignment**



# **IEC Logic Symbol**







#### **Truth Table**

Inputs Function		Outputs				
G	DIR	A Bus	B Bus	ACT245	ACT640	
L	L	Output	Input	A = B	A = B	
L	Н	Input	Output	B = A	B = Ā	
Н	Х	2	7	Z	Z	

X: Don't care

Z: High impedance

# Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	-0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	IIК	±20	mA
Output diode current	I <sub>OK</sub>	±50	mA
DC output current	IOUT	±50	mA
DC V <sub>CC</sub> /ground current	ICC	±200	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: 500 mW in the range of Ta =  $-40^{\circ}$ C to 65°C. From Ta = 65°C to 85°C a derating factor of  $-10 \text{ mW/}^{\circ}$ C should be applied up to 300 mW.

## **Operating Range (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	4.5 to 5.5	V
Input voltage	V <sub>IN</sub>	0 to V <sub>CC</sub>	V
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to 85	°C
Input rise and fall time	dt/dV	0 to 10	ns/V

Note: The operating range is required to ensure the normal operation of the device. Unused inputs and bus inputs must be tied to either VCC or GND. Please connect both bus inputs and the bus outputs with VCC or GND when the I/O of the bus terminal changes by the function. In this case, please note that the output is not short-circuited.

# **Electrical Characteristics**

#### **DC Characteristics**

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40 to 85°C		Unit	
Characteristics	Gymbol			V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Onit	
High-level input voltage	VIH	-			4.5 to 5.5	2.0	_	_	2.0	_	V
Low-level input voltage	V <sub>IL</sub>	_			4.5 to 5.5	_	_	0.8	_	0.8	V
	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA		4.5	4.4	4.5		4.4	_	
High-level output voltage			I <sub>OH</sub> = −24 mA		4.5	3.94	—	—	3.80	—	V
			I <sub>OH</sub> = −75 mA	(Note)	5.5	—	—	—	3.85	—	
	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA		4.5	_	0.0	0.1	_	0.1	
Low-level output voltage			I <sub>OL</sub> = 24 mA	4.5	—	—	0.36	—	0.44	V	
			I <sub>OL</sub> = 75 mA	(Note)	5.5	—	—	—	—	1.65	
3-state output off-state current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$			5.5	_	—	±0.5		±5.0	μΑ
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND			5.5	_	_	±0.1	-	±1.0	μA
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND			5.5	_	—	8.0	_	80.0	μA
	IC	Per input: V <sub>IN</sub> = 3.4 V Other input: V <sub>CC</sub> or GND			5.5	_	_	1.35	_	1.5	mA

Note: This spec indicates the capability of driving 50  $\Omega$  transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

#### AC Characteristics ( $C_L$ = 50 pF, $R_L$ = 500 $\Omega$ , input: $t_r$ = $t_f$ = 3 ns)

Characteristics	Test Condition			Га = 25°С	= 25°C		Ta = −40 to 85°C		
			V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	
Propagation delay	t <sub>pLH</sub>		5.0 ± 0.5	_	5.0	8.0	1.0	9.0	ns
time (Note 2)	t <sub>pHL</sub>		5.0 ± 0.5						115
Propagation delay	t <sub>pLH</sub>		5.0 ± 0.5	—	5.7	8.5	1.0	9.5	ns
time (Note 3)	t <sub>pHL</sub>	—							
Output enable time	t <sub>pZL</sub>		5.0 ± 0.5	—	7.3	12.3	1.0	14.0	ns
Output chable time	t <sub>pZH</sub>								113
Output disable time	t <sub>pLZ</sub>		5.0 ± 0.5	_	6.3	9.7	1.0	11.0	ns
	t <sub>pHZ</sub>								115
Input capacitance	CIN	DIR, G		—	5	10		10	pF
Bus input capacitance	C <sub>I/O</sub>	A <sub>n</sub> , Bn		_	13	_	_	_	pF
Power dissipation	C <sub>PD</sub>	TC74ACT245		_	38	_	_	_	nΕ
capacitance	(Note 1)	TC74ACT640	—	43				рF	

Note 1: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$  (per bit)

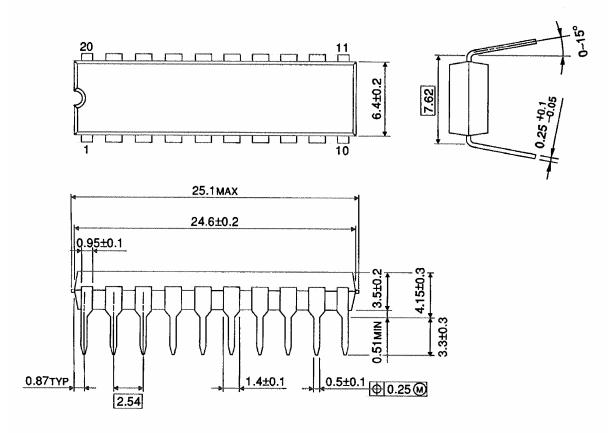
Note 2: For TC74ACT245 only

Note 3: For TC74ACT640 only

#### **Package Dimensions**

DIP20-P-300-2.54A

Unit : mm



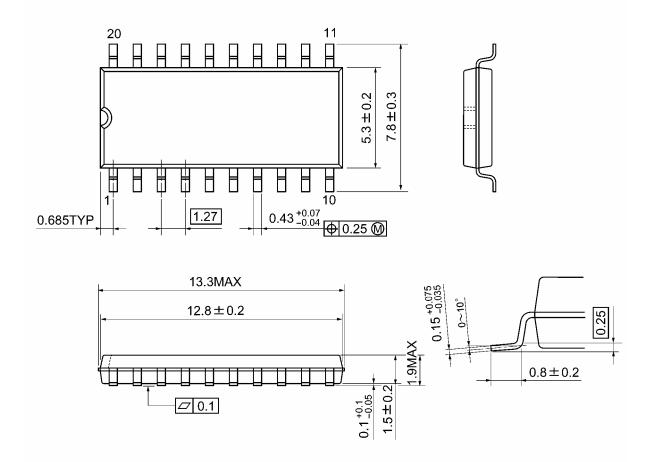
Weight: 1.30 g (typ.)



#### **Package Dimensions**

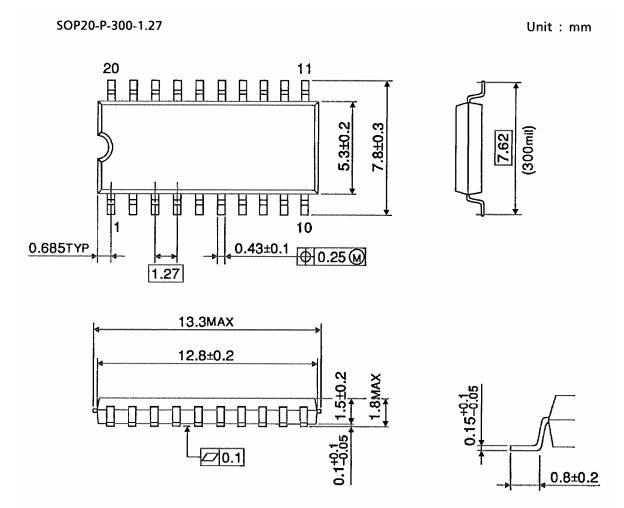
SOP20-P-300-1.27A

Unit: mm



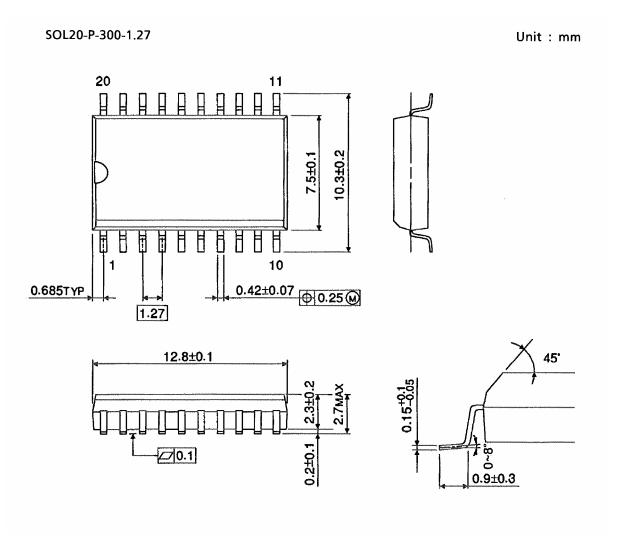
Weight: 0.22 g (typ.)

#### **Package Dimensions**



Weight: 0.22 g (typ.)

## Package Dimensions (Note)



Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

# **TOSHIBA**

Unit: mm

## Package Dimensions

TSSOP20-P-0044-0.65A

20 П 11 || 6.4±0.2 **4.4±0.1** ₿ 10 Ħ Ħ Ħ Ħ Ħ Ħ Ħ Π Π  $0.22\substack{+0.09\\-0.06}$ 0.65 0.325TYP <del>∲</del>0.13∭ 6.9MAX 6.5±0.1 1.2MAX ┲┲╜ 0.15+0.03 \* 0~10° 0.25 1.0±0.05 0.1±0.05 S ∠70.1S (0.5) 0.45~0.75

Weight: 0.08 g (typ.)

#### **RESTRICTIONS ON PRODUCT USE**

20070701-EN

• The information contained herein is subject to change without notice.

TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.

- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.).These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in his document shall be made at the customer's own risk.
- The products described in this document shall not be used or embedded to any downstream products of which manufacture, use and/or sale are prohibited under any applicable laws and regulations.
- Please contact your sales representative for product-by-product details in this document regarding RoHS compatibility. Please use these products in this document in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances. Toshiba assumes no liability for damage or losses occurring as a result of noncompliance with applicable laws and regulations.